## NSN 5961-01-112-5543

Transistor - Page 1 of 1

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View Online at https://aerobasegroup.com/nsn/5961-01-112-5543 **Inclosure Material:** Plastic **Overall Length:** Between 0.360 inches and 0.410 inches **Overall Height:** Between 0.120 inches and 0.190 inches **Overall Width:** Between 0.280 inches and 0.320 inches **Mounting Facility Quantity: Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-202 **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 drain to gate voltage and 80.0 drain to source voltage and 115.0 forward gate to source voltage **Current Rating Per Characteristic:** 2.00 amperes drain current **Power Rating Per Characteristic:** 12.5 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No